

SMD Type 850nm Infrared Emitter

Features

- Small double-end package
- Viewing Angle at X axis (Note3) = $\pm 22.5^{\circ}$
- High reliability
- Good spectral matching to Si photo detector
- RoHS compliance

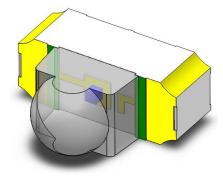
Applications

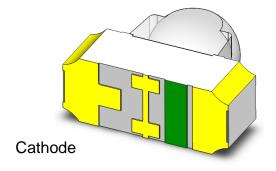
- Infrared sensor
- Infrared Touch Panel Solutions

Description

The HIRP3012W24-E5 is a GaAlAs infrared LED housed in a miniature SMD package. The device has a peak wavelength of 850nm LED spectrally matched with phototransistor or photodiode.

Package Outline





Anode

Schematic

Cathode
$$-$$
 Anode $(-)$



HIRP3012W24-E5 SMD Type 850nm Infrared Emitter

Absolute Maximum Rating at 25°C

Symbol	Parameters	Ratings	Units	Notes
lF	Continuous Forward Current	70	mA	
I _{FP}	Peak Forward Current	0.7	Α	1
VR	Reverse Voltage	5	V	
T _{opr}	Operating Temperature	-40 ~ +85	°С	
T _{stg}	Storage Temperature	-40 ~ +100	°С	
T _{sol}	Soldering Temperature	260	°С	2
P _D	Power Dissipation at(or below) 25°C Free Air Temperature	140	mW	

Electro-Optical Characteristics TA = 25°C (unless otherwise specified)

Optical Characteristics

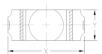
Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
la la	Padient Intensity	I _F =20mA	6.5	11	-	mW/sr	
le	Radiant Intensity	I _F =70mA	-	40	-	11100/51	
λр	Peak Wavelength	I _F =20mA	-	850	-	nm	
Δλ	Spectral Bandwidth	I _F =20mA	-	30	-	nm	
θ1/2	Angle of Half Intensity (X)	- I _F =20mA -	-	±22.5	-	doa	3
	Angle of Half Intensity (Y)		-	±20	-	- deg	

Electrical Characteristics

Symbol	Parameters	Test Conditions	Min	Тур	Max	Units	Notes
\/-	Converd Voltage	I _F =20mA	1.30	1.47	1.7		
V _F Forward Voltage		I _F =70mA	1.40	1.59	2.0	V	
I _R	Reverse Current	V _R =5V	-	-	10	μΑ	

Notes:

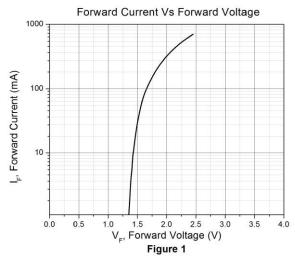
- 1: I_{FP} Conditions--Pulse Width \leq 100 μ s and Duty \leq 1%.
- 2: Soldering time ≤ 5 seconds.
- 3: Test condition:

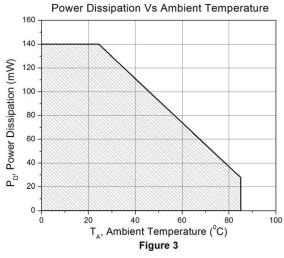


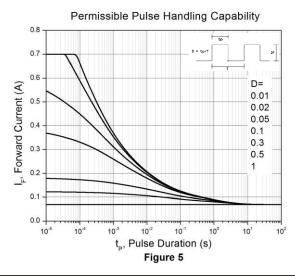


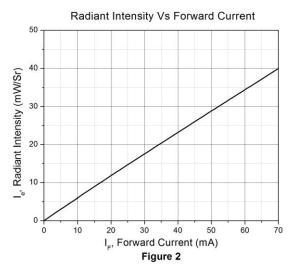
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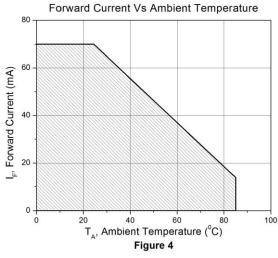
Typical Characteristic Curves

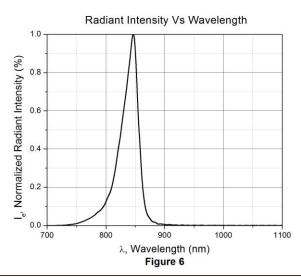










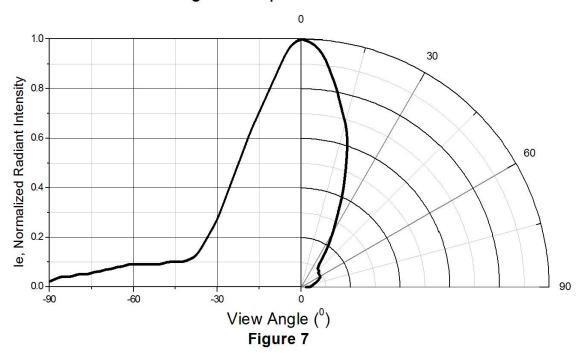




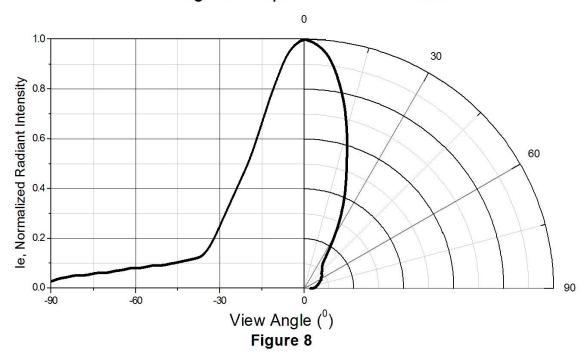
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Typical Characteristic Curves

Angular Displacement at X axis



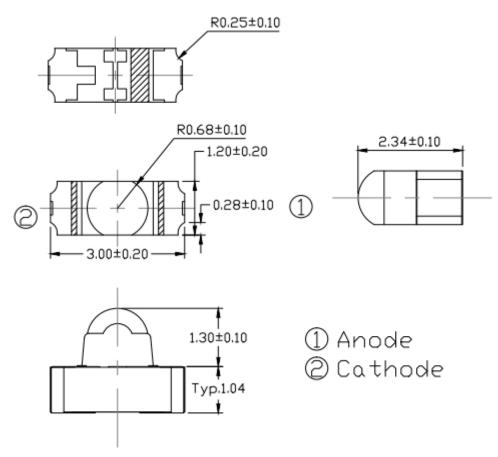
Angular Displacement at Y axis



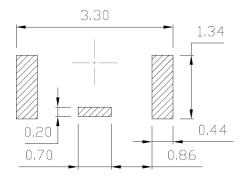


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Package Dimension All dimensions are in mm, unless otherwise stated



Recommended Soldering Mask All dimensions are in mm, unless otherwise stated



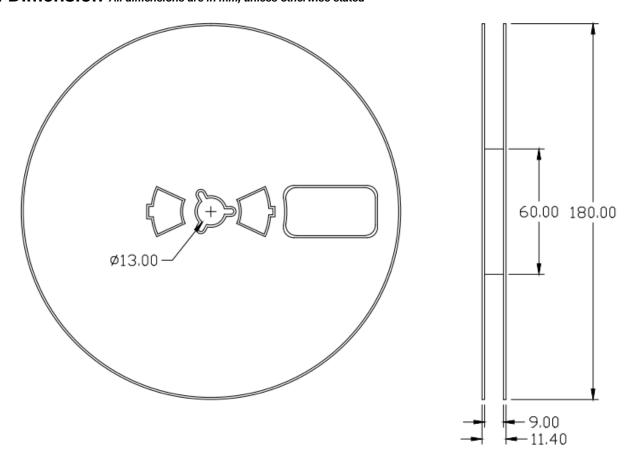
Ordering Information

Part Number	Description	Quantity
HIRP3012W24-E5	Tape & Reel	2000 pcs

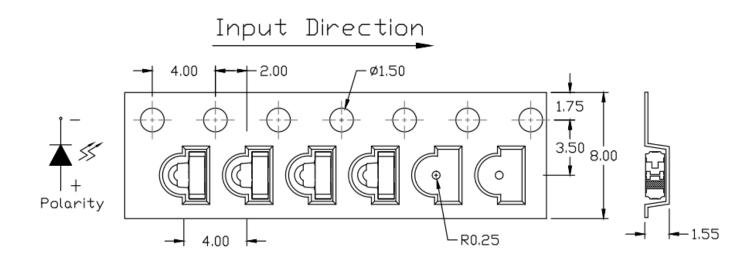


HIRP3012W24-E5 SMD Type 850nm Infrared Emitter

Reel Dimension All dimensions are in mm, unless otherwise stated



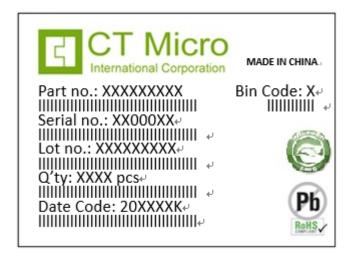
Tape Dimension All dimensions are in mm, unless otherwise stated





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Label Form Specification



Part no: CTM Production Number

Serial no: Production Number

Lot no: Lot number

Q'ty: Packing Quantity

Date Code: Manufacture Date

Bin Code: le Ranks

MADE IN CHINA: Production Place

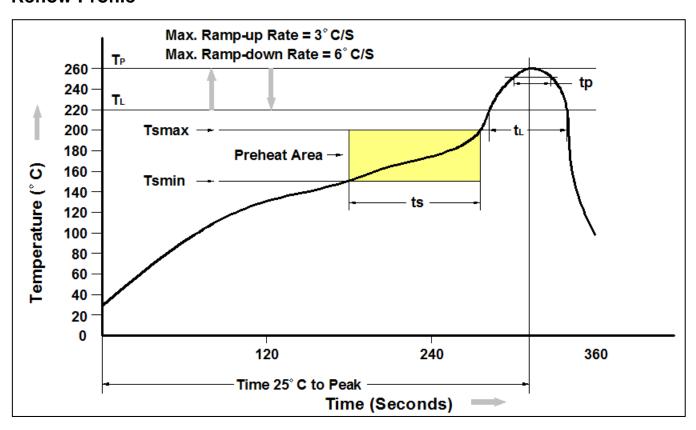
Storage Condition

- 1. Do not open moisture proof bag before the products are ready to use.
- 2. The moisture barrier bag should be stored at 30°C and 90%R.H. max. before opening. Shelf life of non-opened bag is 12 months after the bag sealing date.
- 3. After opening the moisture barrier bag floor life is 168h at 30°C/60%RH. max. Unused LEDs should be resealed into moisture barrier bag. (Refer to J-STD-020 Standard)
- 4. If the moisture absorbent material has faded away or the LEDs have exceeded the storage time, baking treatment should be performed using the J-STD-033 Standard conditions.



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Reflow Profile



Profile Feature	Pb-Free Assembly Profile
Temperature Min. (Tsmin)	150°C
Temperature Max. (Tsmax)	200°C
Time (ts) from (Tsmin to Tsmax)	60-120 seconds
Ramp-up Rate (t∟ to t _P)	3°C/second max.
Liquidous Temperature (T∟)	217°C
Time (t _L) Maintained Above (T _L)	60 – 150 seconds
Peak Body Package Temperature	260°C +0°C / -5°C
Time (t _P) within 5°C of 260°C	30 seconds
Ramp-down Rate (T _P to T _L)	6°C/second max
Time 25°C to Peak Temperature	8 minutes max.



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